

JST132N2-600D 0.5A TRIAC

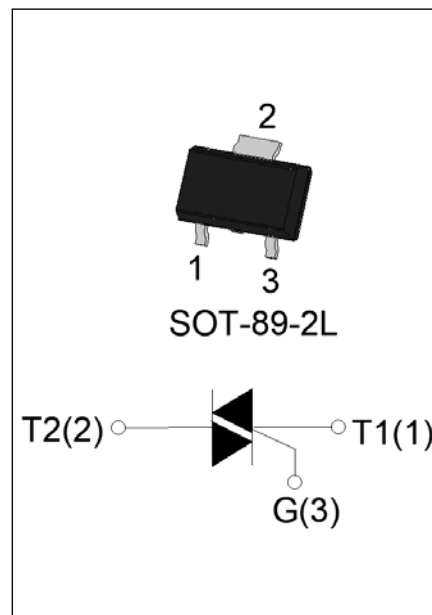
Rev.A.1.1

DESCRIPTION:

The JST132N2-600D triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. Package SOT-89-2L is RoHS compliant.

MAIN FEATURES

Symbol	Value	Unit
$I_{T(RMS)}$	0.5	A
V_{DRM}/V_{RRM}	600	V
$I_{GT\ I}/II/III/IV$	5/5/5/10	mA


ABSOLUTE MAXIMUM RATINGS

Parameter		Symbol	Value	Unit
Storage junction temperature range		T _{stg}	-40-150	℃
Operating junction temperature range		T _j	-40-125	℃
Repetitive peak off-state voltage (T _j =25℃)		V _{DRM}	600	V
Repetitive peak reverse voltage (T _j =25℃)		V _{RRM}	600	V
RMS on-state current (T _c ≤84℃)		I _{T(RMS)}	0.5	A
Non repetitive surge peak on-state current (full cycle , t _p =20ms , T _j =25℃)		I _{TSM}	6	A
Non repetitive surge peak on-state current (full cycle , t _p =16.6ms , T _j =25℃)			6.6	
I ² t value for fusing (t _p =10ms , T _j =25℃)		I ² t	0.18	A ² s
Critical rate of rise of on-state current (I _G =2×I _{GT} , f=100Hz , T _j =125℃)	I - II	di/dt	50	A/μs
	III-IV		20	
Peak gate current (t _p =20μs , T _j =125℃)		I _{GM}	1	A
Average gate power dissipation (T _j =125℃)		P _{G(AV)}	0.1	W
Peak gate power		P _{GM}	5	W
Peak pulse voltage (T _j =25℃; non-repetitive,off-state;FIG.8)		V _{PP}	1.5	kV

ELECTRICAL CHARACTERISTICS ($T_j=25^{\circ}\text{C}$ unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
I_{GT}	$V_D=12\text{V}$ $R_L=33\Omega$	I - II -III	MAX.	5	mA
		IV		10	
V_{GT}		ALL	MAX.	1.3	V
V_{GD}	$V_D=V_{DRM}$ $T_j=125^{\circ}\text{C}$ $R_L=3.3\text{k}\Omega$	ALL	MIN.	0.2	V
I_L	$I_G=1.2I_{GT}$	I -III-IV	MAX.	10	mA
		II		20	
I_H	$I_T=50\text{mA}$		MAX.	10	mA
dV/dt	$V_D=400\text{V}$ Gate Open $T_j=110^{\circ}\text{C}$		MIN.	60	$\text{V}/\mu\text{s}$
$(dV/dt)_c$	$(dI/dt)_c=0.3\text{A/ms}$, $T_j=110^{\circ}\text{C}$		MIN.	5	$\text{V}/\mu\text{s}$
t_{on}	$I_G=20\text{mA}$ $I_A=200\text{mA}$ $I_R=20\text{mA}$ $T_j=25^{\circ}\text{C}$		TYP.	2.5	μs
t_{off}				25	

STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX.)	Unit
V_{TM}	$I_{TM}=0.85\text{A}$ $t_p=380\mu\text{s}$	$T_j=25^{\circ}\text{C}$	1.5	V
V_{TO}	Threshold voltage	$T_j=125^{\circ}\text{C}$	0.98	V
R_D	Dynamic resistance	$T_j=125^{\circ}\text{C}$	362	$\text{m}\Omega$
I_{DRM}	$V_D=V_{DRM}$ $V_R=V_{RRM}$	$T_j=25^{\circ}\text{C}$	5	μA
I_{RRM}		$T_j=125^{\circ}\text{C}$	0.15	mA

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	junction to case (AC)	60	$^{\circ}\text{C}/\text{W}$
$R_{th(j-a)}$	junction to ambient (AC, in free air, $S=5\text{cm}^2$)	100	$^{\circ}\text{C}/\text{W}$

ORDERING INFORMATION

J	ST	132	N2	-600	D
JieJie Microelectronics Co., Ltd.	Triacs	$I_T(RMS):0.5A$	N2:SOT-89-2L	$600:V_{DRM}/V_{RRM} \geq 600V$	D: $I_{GT1-3} \leq 5mA$ $I_{GT4} \leq 10mA$

MARKING

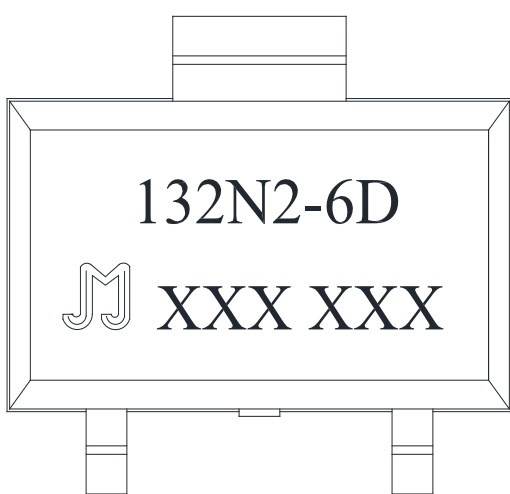
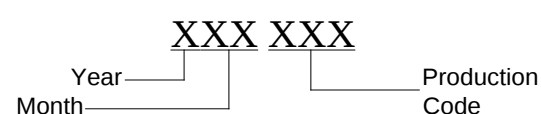
	
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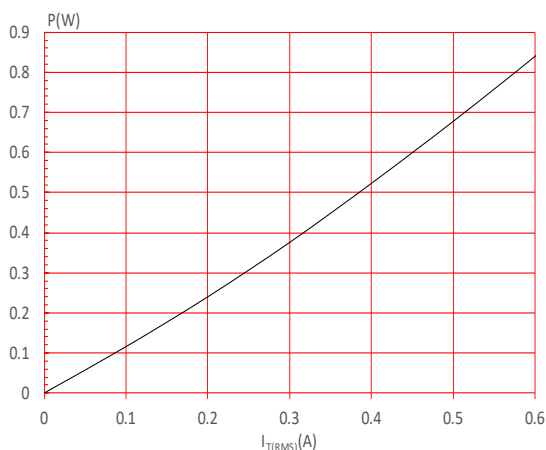
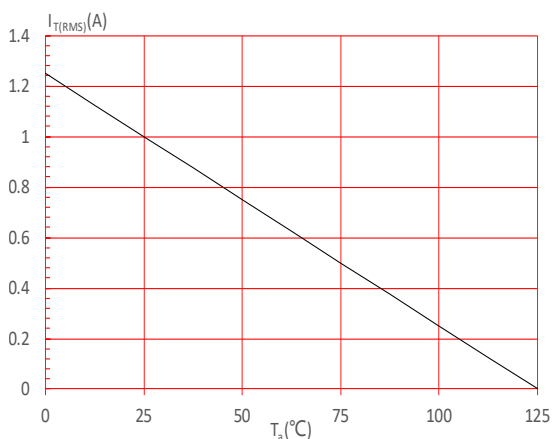
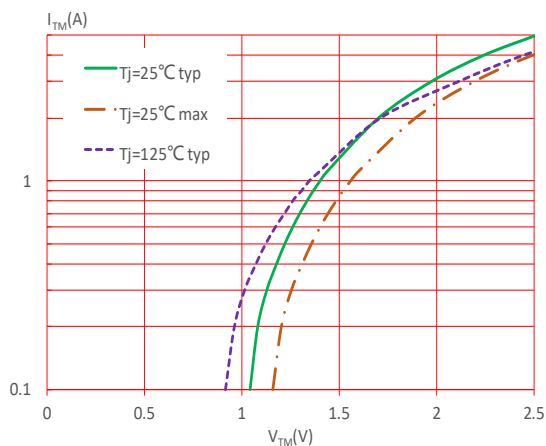
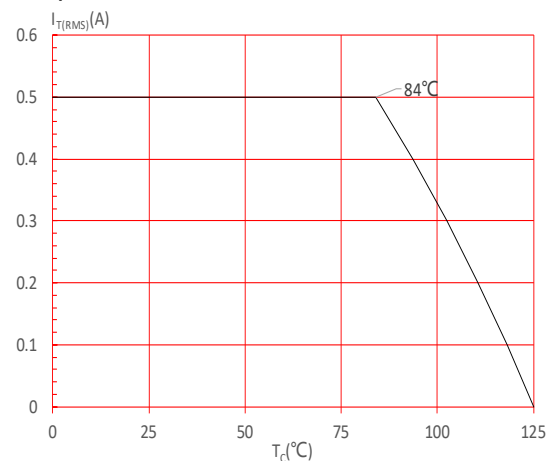
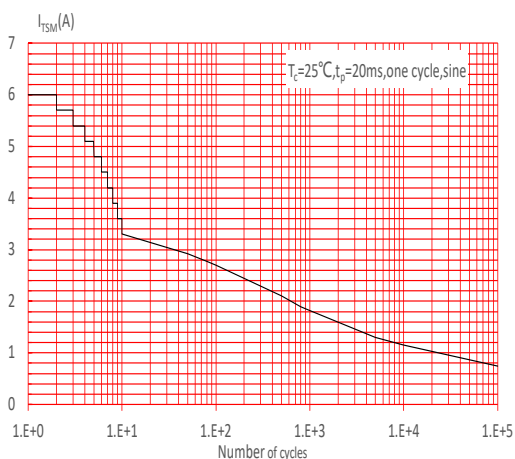
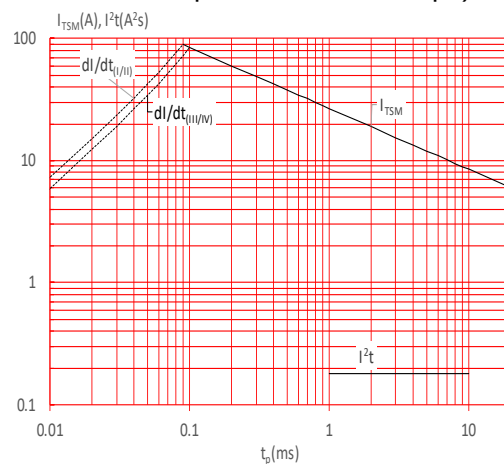
FIG.1: Maximum power dissipation versus RMS on-state current

FIG.3: RMS on-state current versus ambient temperature (printed circuit board FR4, copper thickness: 35μm) (full cycle)

FIG.5: On-state characteristics

FIG.2: RMS on-state current versus case temperature

FIG.4: Surge peak on-state current versus number of cycles

FIG.6: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 20\text{ms}$, and corresponding value of I^2t (I - II: $di/dt < 50\text{A}/\mu\text{s}$; III-IV: $di/dt < 20\text{A}/\mu\text{s}$)


FIG.7: Relative variations of gate trigger current, holding current and latching current versus junction temperature

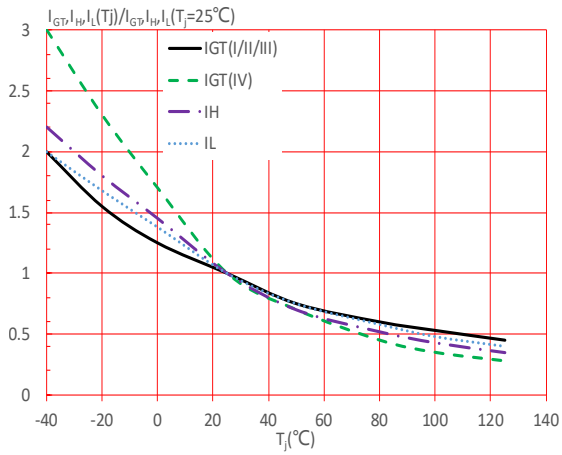
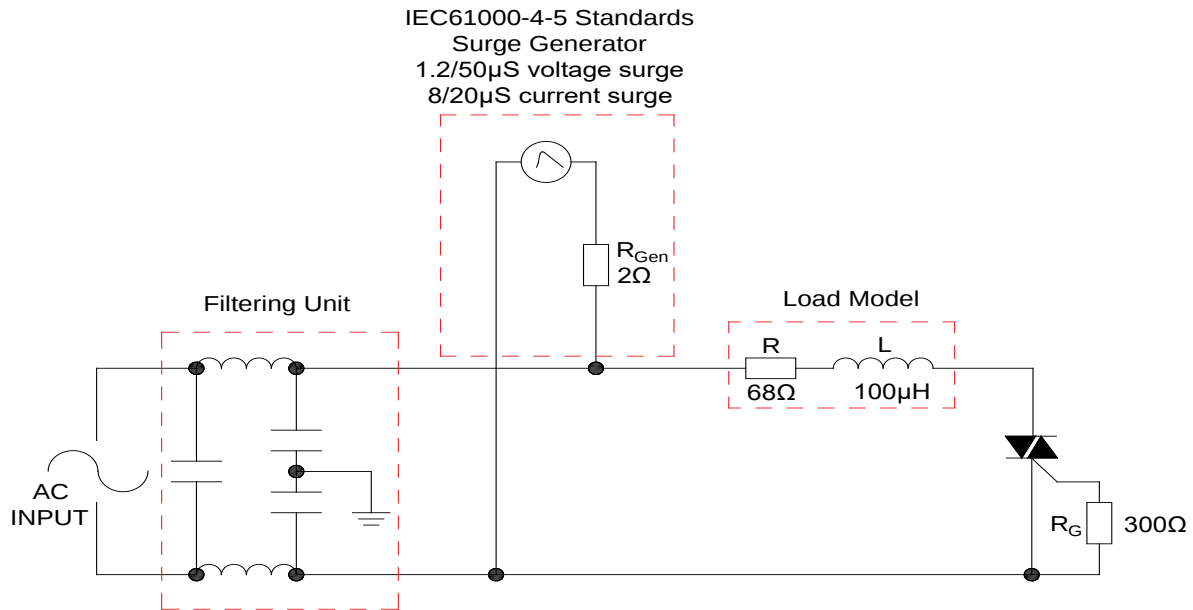
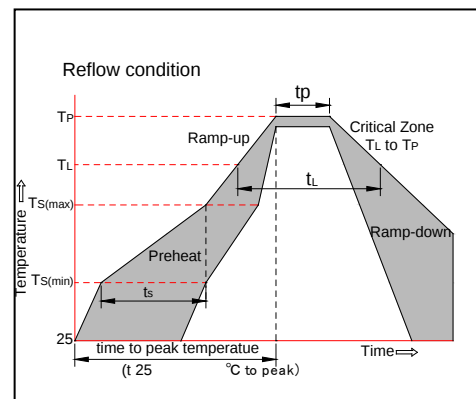


FIG.8: Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



SOLDERING PARAMETERS

Reflow Condition		Pb-Free assembly (see figure at right)
Pre Heat	-Temperature Min (T _{s(min)})	+150°C
	-Temperature Max(T _{s(max)})	+200°C
	-Time (Min to Max) (ts)	60-180 secs.
Average ramp up rate (Liquidus Temp (T _L) to peak)		3°C/sec. Max
T _{s(max)} to T _L - Ramp-up Rate		3°C/sec. Max
Reflow	-Temperature(T _L) (Liquidus)	+217°C
	-Temperature(t _L)	60-150 secs.
Peak Temp (T _p)		+260(+0/-5)°C
Time within 5°C of actual Peak Temp (t _p)		20-40secs.
Ramp-down Rate		6°C/sec. Max
Time 25°C to Peak Temp (T _P)		8 min. Max
Do not exceed		+260°C



ORDERING INFORMATION

Order code	Voltage $V_{\text{DRM}}/V_{\text{RRM}}$ (V)	IGT(mA)		Package	Base qty. (pcs)	Delivery mode
		I - II - III	IV			
JST132N2-600D	600	5	10	SOT-89-2L	4,000	Tape & Reel

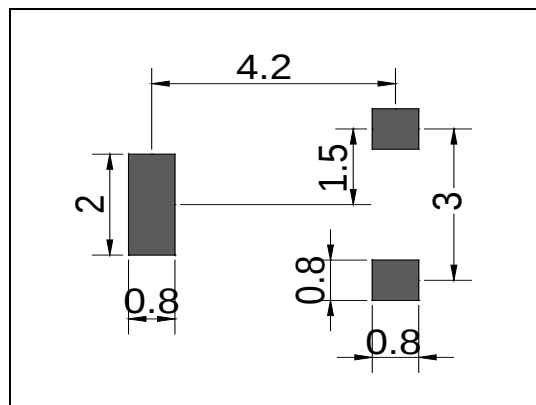
Document Revision History

Date	Revision	Changes
Apr.14, 2023	A.1.0	Last updated
Oct.16, 2025	A.1.1	Revise PACKAGE MECHANICAL DATA

Technical drawing of a rectangular box with dimensions labeled in blue. The drawing includes three views: a top view, a front view, and a side view. The dimensions are as follows:

- Top View:** Dimensions A (height of the top flange), A1 (total height), B (width of the top flange), and D (total width).
- Front View:** Dimensions E (height of the main body), F (width of the main body), F1 (width of the bottom flange), B1 (width of the bottom flange), and J (total height).
- Side View:** Dimensions C (width of the top flange), K1 (width of the top flange), H (height of the main body), G (width of the main body), and K (width of the bottom flange).

FOOTPRINT-SOT-89-2L (dimensions in mm)



PACKAGE	OUTLINE	REEL (PCS)	PER CARTON (PCS)	TAPE & REEL
SOT-89-2L	TAPING	4,000	40,000	13 inch

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